



Silicon Dual Schottky Power Rectifier

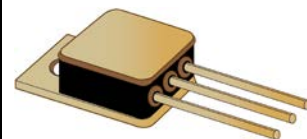
30 Amp, 45 Volt

Qualified per MIL-PRF-19500/608

Qualified Levels:
JAN, JANTX, and
JANTXV

DESCRIPTION

This Dual Schottky rectifier device is military qualified up to a JANTXV level for high-reliability applications. This TO-254 packaged product is available in three polarity options.



TO-254AA Package

Important: For the latest information, visit our website <http://www.microsemi.com>.

FEATURES

- JEDEC registered 1N6660.
- Hermetically isolated TO-254AA package.
- Available in standard, reverse, common cathode, common anode and doubler configurations.
- JAN, JANTX, and JANTXV qualifications are available per MIL-PRF-19500/608.
- RoHS compliant versions available (commercial grade only).

APPLICATIONS / BENEFITS

- High frequency operation.
- Low forward voltage drop.

MAXIMUM RATINGS @ $T_A = +25^\circ\text{C}$ unless otherwise noted.

Parameters/Test Conditions	Symbol	Value per diode		Unit
Junction and Storage Temperature	T_J and T_{STG}	-65 to +150		$^\circ\text{C}$
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	Die 1	Die 2	$^\circ\text{C/W}$
1N6660CCT1		1.65	1.65	
1N6660CAT1		2.8	2.8	
1N6660DT1		2.8	1.65	
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	50		$^\circ\text{C/W}$
Working Peak Reverse Voltage	V_{RWM}	45		V
DC Blocking Voltage	V_R	45		V
Surge Peak Forward Current @ $t_p = 8.3$ ms half-sine wave	I_{FSM}	300		A
Average Rectified Output Current ⁽¹⁾	I_O	15		A

Note: 1. See [Figures 1 and 2](#) for derating of entire package (30 Amps).

MSC – Lawrence
6 Lake Street,
Lawrence, MA 01841
Tel: 1-800-446-1158 or
(978) 620-2600
Fax: (978) 689-0803

MSC – Ireland
Gort Road Business Park,
Ennis, Co. Clare, Ireland
Tel: +353 (0) 65 6840044
Fax: +353 (0) 65 6822298

Website:
www.microsemi.com

MECHANICAL and PACKAGING

- CASE: Nickel plated CRS steel.
- TERMINALS: Ceramic feed-through, hot solder dip, Ni plated Alloy 52, copper core. "e3" available for commercial only (pure tin dip).
- MARKING: Part number, date code, and polarity symbol.
- POLARITY: See [Schematic](#) on last page.
- WEIGHT: Approximately 6.5 grams.
- See [Package Dimensions](#) on last page.

PART NOMENCLATURE

JAN 1N6660 R T1 (e3)

Reliability Level

JAN = JAN Level
JANTX = JANTX Level
JANTXV = JANTXV Level
Blank = Commercial

JEDEC type number
RoHS Compliance

e3 = RoHS Compliant ([available on commercial grade only](#))
Blank = non-RoHS Compliant

TO-254 Package Type
Polarity

Blank = standard
R = reverse
CA = Common Anode
CC = Common Cathode
D = Doubler

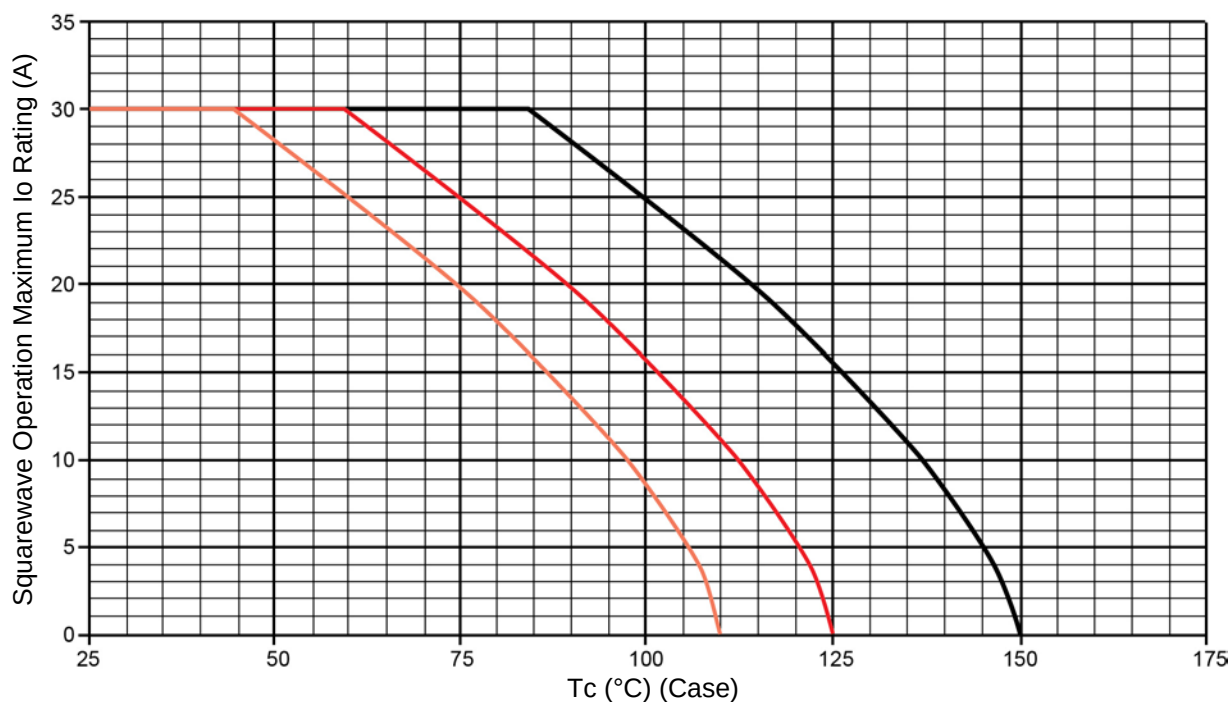
SYMBOLS & DEFINITIONS

Symbol	Definition
C	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage.
f	frequency
I _F	Forward Current: The dc current flowing from the external circuit into the anode terminal.
I _{FSM}	Surge Peak Forward Current: The forward current including all nonrepetitive transient currents but excluding all repetitive transients (ref JESD282-B)
I _O	Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.
I _R	Reverse Current: The dc current flowing from the external circuit into the cathode terminal at the specified voltage V _R .
V _{RWM}	Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes known historically as PIV.
V _F	Forward Voltage: A positive dc anode-cathode voltage the device will exhibit at a specified forward current.
V _R	Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region.

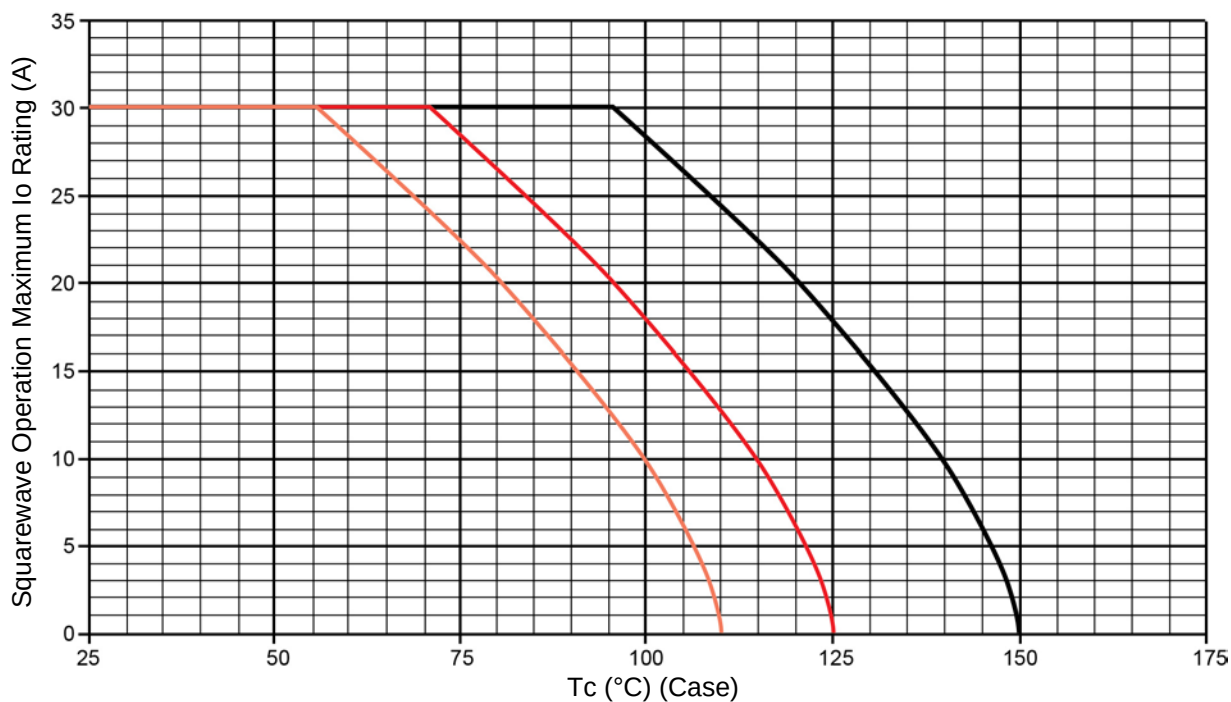
ELECTRICAL CHARACTERISTICS @ $T_A = +25\text{ }^{\circ}\text{C}$ unless otherwise noted

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
CHARACTERISTICS per Leg				
Forward Voltage* $I_F = 5\text{ A}$ $I_F = 15\text{ A}$ $I_F = 30\text{ A}$ $I_F = 15\text{ A}, T_A = -55\text{ }^{\circ}\text{C}$	V_F		0.55 0.75 1.00 0.80	V
Reverse Current $V_R = 45\text{ V}$ $V_R = 45\text{ V}, T_J = +125\text{ }^{\circ}\text{C}$	I_R		1.0 40	mA
Junction Capacitance $V_R = 5\text{ V}$ $f = 1\text{ MHz}, V_{SIG} = 50\text{ mV (p-p) (max)}$	C		2000	pF

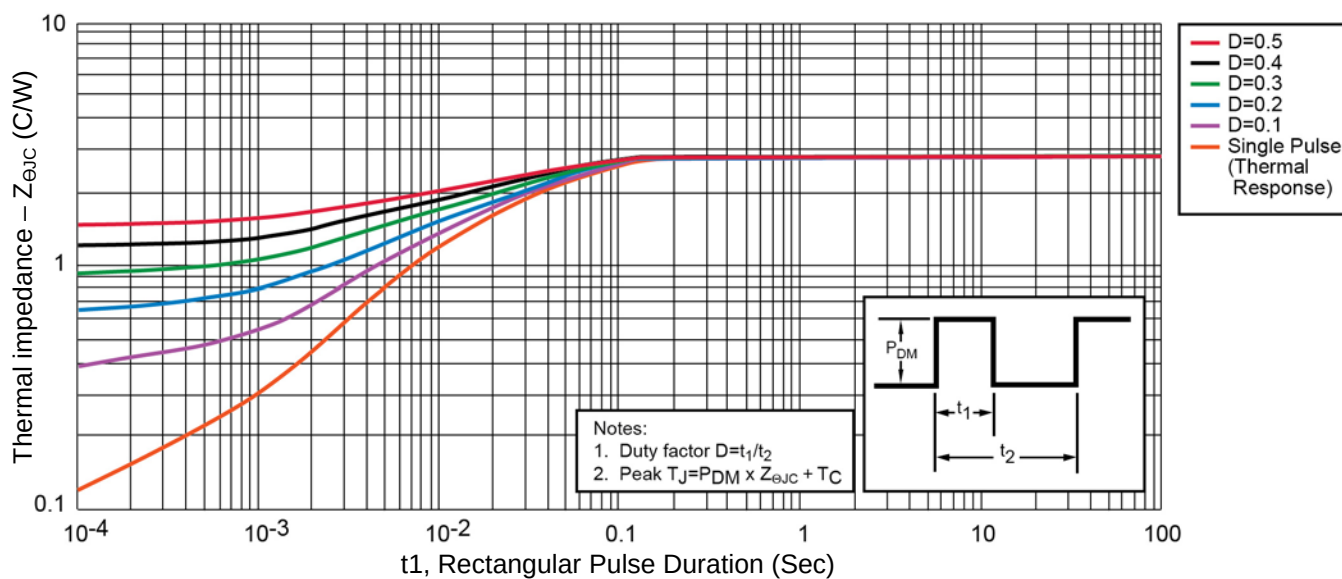
* Pulse test: Pulse width 300 μsec , duty cycle 2%.

GRAPHS

FIGURE 1

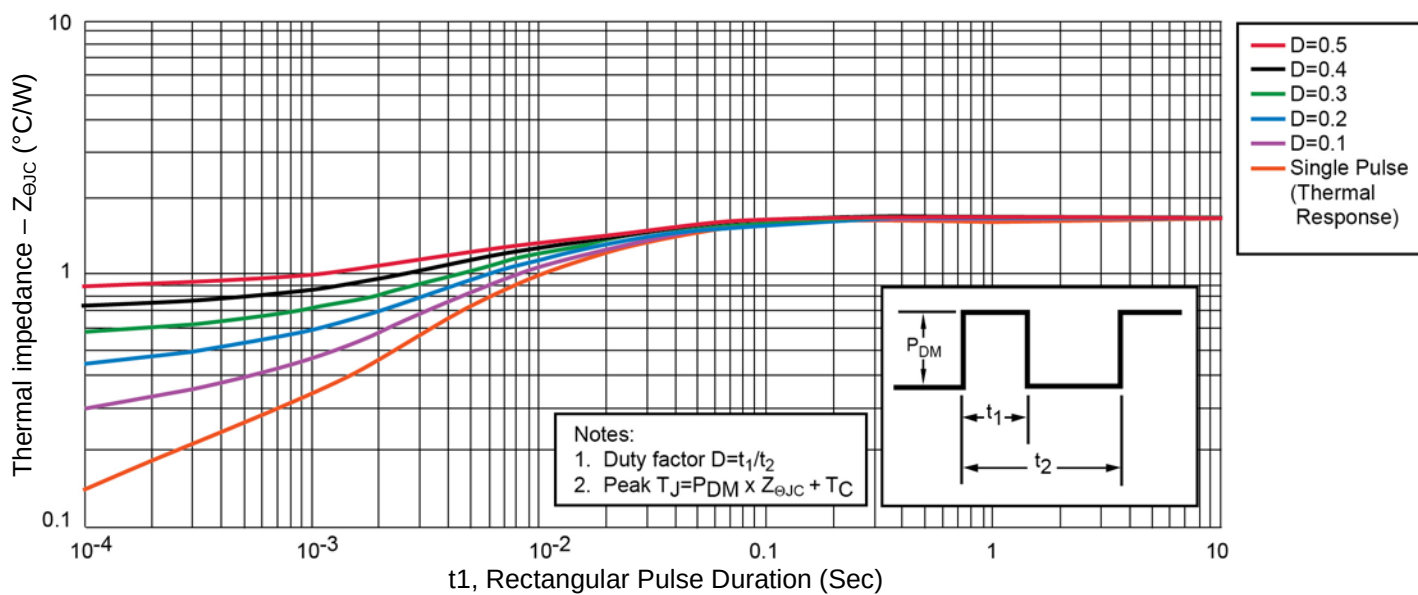
Temperature-current derating curve (1N6660, 1N6660CCT1, entire package)


FIGURE 2

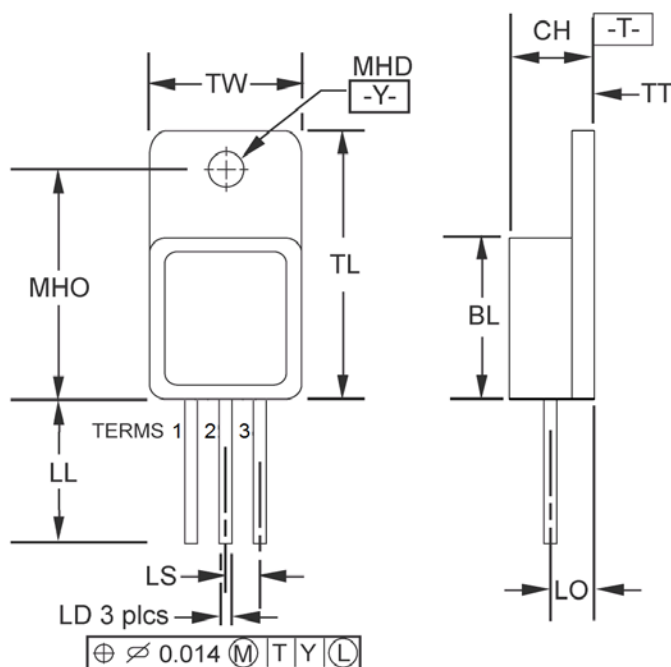
Temperature-current derating curve (1N6660R, 1N6660CAT1, 1N6660DT1, entire package)

GRAPHS

FIGURE 3

Thermal impedance for each leg 1N6660CAT1, 1N6660DT1, die 1, and 1N6660R


FIGURE 4

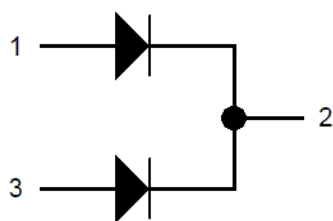
Thermal impedance for each leg 1N6660CCT1, 1N6660DT1, die 2, and 1N6660

PACKAGE DIMENSIONS


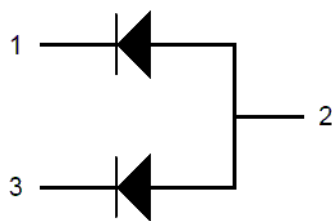
Ltr	Dimensions			
	Inch		Millimeters	
	Min	Max	Min	Max
BL	0.535	0.545	13.59	13.84
CH	0.249	0.260	6.32	6.60
LD	0.035	0.045	0.89	1.14
LL	0.510	0.570	12.95	14.48
LO	0.150 BSC		3.81 BSC	
LS	0.150 BSC		3.81 BSC	
MHD	0.139	0.149	3.53	3.78
MHO	0.665	0.685	16.89	17.40
TL	0.790	0.800	20.07	20.32
TT	0.040	0.050	1.02	1.27
TW	0.535	0.545	13.59	13.84

NOTES:

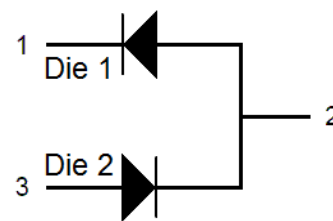
1. Dimensions are in inches.
2. Millimeters are given for information only.
3. In accordance with ASME Y14.5M, diameters are equivalent to Φ x symbology.

SCHEMATICS

1N6660 & 1N6660CCT1

TERM 1 = ANODE
TERM 2 = CATHODE
TERM 3 = ANODE


1N6660R & 1N6660CAT1

TERM 1 = CATHODE
TERM 2 = ANODE
TERM 3 = CATHODE


1N6660DT1

TERM 1 = ?
TERM 2 = ?
TERM 3 = ?

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[1N6660](#) [1N6660R](#) [JAN1N6660DT1](#) [1N6660DT1](#) [1N6660CAT1](#) [1N6660CCT1](#) [JANTXV1N6660](#) [JANTX1N6660](#)

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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9